

HIGH RELIABILITY HYBRID RADIATION TOLERANT DC-DC CONVERTERS

DESCRIPTION

The SVTR series of high reliability DC-DC converters is operable over the full military temperature range (-55 °C to +125 °C) with no power derating. Paramount to the SVTR series is a magnetic feedback circuit that is radiation immune. Operating at a nominal fixed frequency of 500 kHz, these regulated, isolated units utilize well-controlled undervoltage lockout circuitry to eliminate slow start-up problems.

The SVTR series is specifically designed for the harsh radiation environment of space applications. Performance is guaranteed through the use of hardened semiconductor components, radiation lot acceptance testing (RLAT) of non-hardened components and analysis. The SVTR series has been characterized for Total Ionizing Dose (TID) performance including Enhanced Low Dose Rate Sensitivity (ELDRS) and for Single Event Effects (SEE) according to VPT's DLA approved Radiation Hardness Assurance (RHA) plan per MIL-PRF-38534, Appendix G. Characterization is performed at both the component level and at the SVTR series hybrid converter level.

These converters are designed and manufactured in a facility qualified to ISO9001 and certified to MIL-PRF-38534 Class H and Class K and MIL-STD-883.

This product may incorporate one or more of the following U.S. patents:

5,784,266 5,790,389 5,963,438 5,999,433 6,005,780 6,084,792 6,118,673

FEATURES

- Guaranteed TID Performance to 30 krad(Si) including ELDRS, per VPT's RHA plan specified per MIL-PRF-38534, Appendix G, Level P with 2X margin.
- Characterized to 44 MeV-cm²/mg with minor transients only; no dropouts, shutdowns, latch up or burn out.
- High Reliability
- Very Low Output Noise
- Wide Input Voltage Range: 15 to 50 Volts per MIL-STD-704
- Up to 40 Watts Output Power
- Radiation Immune Magnetic Feedback Circuit
- NO Use of Optoisolators
- Undervoltage Lockout
- Current Limit and Short Circuit Protection
- High Input Transient Voltage: 80 Volts for 1 sec per MIL-STD-704A
- Precision Seam Seal Hermetic Package
- High Power Density: > 40 W/in³
- Custom Modified Versions May Be Available
- Additional Environmental Screening Available
- Meets MIL-STD-461 Revisions C, D, E and F EMC Requirements When Used With VPT's EMI Filters
- Flanged and Non-flanged Versions Available.
- MIL-PRF-38534 Element Evaluated Components
- Worst Case analysis, Stress, Radiation, and Reliability reports available¹

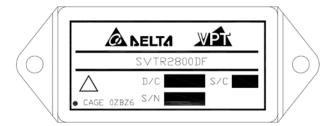


Figure 1 – SVTR2800D / SVTR2800DF DC-DC Converter (Exact marking may differ from that shown)

¹Subject to all export restrictions and export regulations including but not limited to the Export Administration and Foreign Assets Control Regulations. Further restrictions may apply contact VPT for details.



 $SPECIFICATIONS \ (T_{CASE} = -55^{\circ}C \ to \ +125^{\circ}C, \ V_{IN} = +28V \pm 5\%, \ Full \ Load^{5}, \ Unless \ Otherwise \ Specified)$

ABSOLUTE MAXIMUM RATINGS

Input Voltage (Continuous) $50 V_{DC}$ Input Voltage (Transient, 1 second) 80 Volts Output Power¹ 40 Watts Power Dissipation (Full Load, $T_{CASE} = +125^{\circ}C$) 13 Watts ESD Rating per MIL-PRF-38534 3A

Junction Temperature Rise to Case

Storage Temperature

+15°C -65°C to +150°C

Lead Solder Temperature (10 seconds)

270°C

Weight (Maximum) (Un-Flanged / Flanged)

(52 / 55) Grams

Parameter		O = 11 11 1 = 11 8		SVTR2805I)	,	SVTR2812I)	Units
		Conditions ⁸	Min	Тур	Max	Min	Тур	Max	
STATIC									_
INPUT		Continuous	15	28	50	15	28	50	V
Voltage ⁴		Transient, 1 sec	-	-	80	-	-	80	V
Current		Inhibited	-	4	6	-	4	6	mA
Current		No Load	-	60	90	-	60	90	mA
Ripple Current		Full Load⁵, 20Hz to 10MHz	<u>-</u>	30	50	-	30	50	mA _{p-p}
Ripple Current		End-of-Life	-	-	70	-	-	70	mA_{p-p}
Inhibit Pin Input⁴			0	-	1.5	0	-	1.5	V
Inhibit Pin Open Circuit Vol	tage⁴		9.0	11.0	13.0	9.0	11.0	13.0	V
UVLO Turn On			12.0	-	14.8	12.0	-	14.8	V
UVLO Turn Off⁴			11.0	-	14.5	11.0	-	14.5	V
	+V _{OUT}	T _{CASE} = 25°C	4.95	5.0	5.05	11.88	12.0	12.12	V
	$+V_{OUT}$	T_{CASE} = -55°C to +125°C	4.925	5.0	5.075	11.82	12.0	12.18	V
OUTPUT	$+V_{OUT}$	End-of-Life	4.89	-	5.10	11.66	-	12.30	V
Voltage ⁵	$-V_{\text{OUT}}$	T _{CASE} = 25°C	4.80	5.0	5.20	11.80	12.0	12.20	V
	$-V_{\text{OUT}}$	T _{CASE} = -55°C to +125°C	4.70	5.0	5.30	11.64	12.0	12.36	V
	$-V_{\text{OUT}}$	End-of-Life	4.665	-	5.325	11.48	-	12.48	V
Power ^{3,6}	Total		0	-	30	0	-	40	W
	$\pm V_{\text{OUT}}$	Either Output	0	-	21	0	-	28	W
Current ^{3,6}	$\pm V_{\text{OUT}}$	Either Output	0	-	4.2	0	-	2.33	Α
Ripple Voltage	$\pm V_{\text{OUT}}$	Full Load⁵, 20Hz to 10MHz	-	30	60	-	25	50	mV_{p-p}
Line Degulation	+V _{OUT}	V _{IN} = 16V to 40V	-	2	20	-	2	20	mV
Line Regulation	$-V_{OUT}$	V _{IN} = 16V to 40V	-	25	200	-	25	200	mV
Load Decidation	+V _{OUT}	No Load to Full Load⁵	-	5	50	-	2	50	mV
Load Regulation	$-V_{OUT}$	No Load to Full Load ^{5,7}	-	30	200	-	20	200	mV
Cross Regulation	-V _{OUT}	+Load 70%, -Load 30% +Load 30%, -Load 70%	-	360	650	-	430	650	mV
EFFICIENCY		Full Load⁵	73	79	-	78	84	-	%
LOAD FALIL T DOWED DIGGIE	A.T.O.	Overload ⁴	-	-	16	-	-	14	W
LOAD FAULT POWER DISSIP	ATION	Short Circuit	-	-	16	-	-	14	W
CAPACITIVE LOAD⁴	CAPACITIVE LOAD ⁴		-	-	500	-	-	500	μF
SWITCHING FREQUENCY			400	500	550	400	500	550	kHz
SYNC FREQUENCY RANGE		V _H - V _L = 5V, DC = 20-80%	6 500	-	600	500	-	600	kHz
ISOLATION		500 V _{DC} , T _{CASE} = 25°C	100	-	-	100	-	-	ΜΩ
MTBF (MIL-HDBK-217F)		SF @ T _C = 55°C	-	752	-	-	752	-	kHrs

See notes next page.



SPECIFICATIONS ($T_{CASE} = -55^{\circ}C$ to $+125^{\circ}C$, $V_{IN} = +28V \pm 5\%$, Full Load⁵, Unless Otherwise Specified)

ABSOLUTE MAXIMUM RATINGS			
Input Voltage (Continuous)	50 V _{DC}	Junction Temperature Rise to Case	+15°C
Input Voltage (Transient, 1 second)	80 Volts	Storage Temperature	-65°C to +150°C
Output Power ¹	40 Watts	Lead Solder Temperature (10 seconds)	270°C
Power Dissipation (Full Load, T _{CASE} = +125°C)	13 Watts	Weight (Maximum) (Un-Flanged / Flanged)	(52 / 55) Grams
ESD Rating per MIL-PRF-38534	3A		

Parameter		Conditions ⁸	SVTR2805D			SVTR2812D			Units
		Conditions	Min	Тур	Max	Min	Тур	Max	Units
DYNAMIC									
Load Step Output Transient	$\pm V_{\text{OUT}}$	Half Load to Full Load	-	100	400	-	300	450	mV_{PK}
Load Step Recovery ²		Hall Load to Full Load	-	100	350	-	120	400	μSec
Line Step Output Transient ⁴	±V _{OUT}	V _{IN} = 16V to 40V	-	300	600	-	500	900	mV_{PK}
Line Step Recovery ^{2, 4}		V _{IN} = 16V to 40V	-	300	500	-	300	500	μSec
Turn On Delay	±V _{OUT}	V _{IN} = 0V to 28V	-	10	20	-	10	20	mSec
Turn On Overshoot		V _{IN} - UV 10 20V	-	0	25	-	0	50	mV_{PK}

Notes: 1. Dependant on output voltage.

- 2. Time for output voltage to settle within 1% of its nominal value.
- 3. Derate linearly to 0 at 135°C.
- 4. Verified by qualification testing.
- 5. Half load at $+V_{OUT}$ and half load at $-V_{OUT}$.
- 6. Up to 70% of the total power or current can be drawn from any one of the two outputs.
- 7. 5% Load to Full Load at -55°C.
- 8. End-of-Life performance includes aging and radiation degradation and is within standard limits except where noted.



SPECIFICATIONS (T_{CASE} = -55°C to +125°C, V_{IN} = +28V ± 5%, Full Load⁵, Unless Otherwise Specified)

ABSOLUTE MAXIMUM RATINGS							
Input Voltage (Continuous)	50 V _{DC}	Junction Temperature Rise to Case	+15°C				
Input Voltage (Transient, 1 second)	80 Volts	Storage Temperature	-65°C to +150°C				
Output Power ¹	40 Watts	Lead Solder Temperature (10 seconds)	270°C				
Power Dissipation (Full Load, T _{CASE} = +125°C)	13 Watts	Weight (Maximum) (Un-Flanged / Flanged)	(52 / 55) Grams				
ESD Rating per MIL-PRF-38534	3A						

Parameter		Conditions ⁸	:	SVTR2815D			
		Conditions	Min	Тур	Max	Units	
STATIC							
INPUT		Continuous	15	28	50	V	
Voltage⁴		Transient, 1 sec	-	-	80	V	
Current		Inhibited	-	4	6	mA	
Current		No Load	-	60	90	mA	
Ripple Current		Full Load ⁵ , 20Hz to 10MHz	-	25	50	mA_{p-p}	
Rippie Current		End-of-Life	-	-	70	mA_{p-p}	
Inhibit Pin Input⁴			0	-	1.5	V	
Inhibit Pin Open Circuit Vo	oltage⁴		9.0	11.0	13.0	V	
UVLO Turn On			12.0	-	14.8	V	
UVLO Turn Off⁴			11.0	-	14.5	V	
	+V _{OUT}	T _{CASE} = 25°C	14.85	15.0	15.15	V	
OUTPUT Voltage ⁵	$+V_{OUT}$	$T_{CASE} = -55^{\circ}C$ to $+125^{\circ}C$	14.70	15.0	15.30	V	
	$+V_{OUT}$	End-of-Life	14.565	-	15.4	V	
	$-V_{OUT}$	T _{CASE} = 25°C	14.70	15.0	15.30	V	
	$-V_{OUT}$	T _{CASE} = -55°C to +125°C	14.55	15.0	15.45	V	
	$-V_{OUT}$	End-of-Life	14.415	-	15.55	V	
Power ^{3,6}	Total		-	-	40	W	
Power	$\pm V_{\text{OUT}}$	Either Output	-	-	28	W	
Current ^{3,6}	±V _{OUT}	Either Output	-	-	1.87	Α	
Ripple Voltage	$\pm V_{\text{OUT}}$	Full Load ⁵ , 20Hz to 10MHz	-	25	50	mV_{p-p}	
Line Deputation	+V _{OUT}	V _{IN} = 16V to 40V	-	2	20	mV	
Line Regulation	$-V_{OUT}$	V _{IN} = 16V to 40V	-	65	200	mV	
Load Dogulation	+V _{OUT}	No Load to Full Load⁵	-	2	50	mV	
Load Regulation	$-V_{OUT}$	No Load to Full Load ^{5,7}	-	35	200	mV	
Cross Regulation	-V _{out}	+Load 70%, -Load 30% +Load 30%, -Load 70%	-	420	650	mV	
EFFICIENCY		Full Load ⁵	78	84	-	%	
LOAD FAULT POWER DISSIPATION		Overload ⁴	-	-	14	W	
		Short Circuit	-	-	14	W	
CAPACITIVE LOAD⁴		Either Output	-	-	500	μF	
SWITCHING FREQUENCY		•	400	500	550	kHz	
SYNC FREQUENCY RANGE		V _H - V _L = 5V, DC = 20-80%	500	-	600	kHz	
ISOLATION		500 V _{DC} , T _{CASE} = 25°C	100	-	-	МΩ	
MTBF (MIL-HDBK-217F)		SF @ T _C = 55°C	-	752	-	kHrs	

See notes next page.



SPECIFICATIONS (T_{CASE} = -55°C to +125°C, V_{IN} = +28V ± 5%, Full Load⁵, Unless Otherwise Specified)

ABSOLUTE MAXIMUM RATINGS			
Input Voltage (Continuous) Input Voltage (Transient, 1 second)	50 V _{DC} 80 Volts	Junction Temperature Rise to Case Storage Temperature	+15°C -65°C to +150°C
Output Power ¹	40 Watts	Lead Solder Temperature (10 seconds)	270°C
Power Dissipation (Full Load, T _{CASE} = +125°C)	13 Watts	Weight (Maximum) (Un-Flanged / Flanged)	(52 / 55) Grams
ESD Rating per MIL-PRF-38534	3A		

Parameter		Conditions ⁸		Units		
		Conditions	Min	Тур	Max	Units
DYNAMIC						
Load Step Output Transient	$\pm V_{\text{OUT}}$	Half Load to Full Load	-	280	500	mV_{PK}
Load Step Recovery ²		Haif Load to Full Load	-	100	300	μSec
Line Step Output Transient4	±V _{OUT}	\/ = 16\/ to 10\/	-	500	900	mV_{PK}
Line Step Recovery ^{2, 4}		V_{IN} = 16V to 40V	-	300	500	μSec
Turn On Delay	±V _{OUT}	\/ = 0\/ to 20\/	-	10	20	mSec
Turn On Overshoot		$V_{IN} = 0V \text{ to } 28V$	-	0	50	mV_{PK}

Notes: 1. Dependant on output voltage.

- 2. Time for output voltage to settle within 1% of its nominal value.
- 3. Derate linearly to 0 at 135°C.
- 4. Verified by qualification testing.
- 5. Half load at $+V_{OUT}$ and half load at $-V_{OUT}$.
- 6. Up to 70% of the total power or current can be drawn from any one of the two outputs.
- 7. 5% Load to Full Load at -55°C.
- 8. End-of-Life performance includes aging and radiation degradation and is within standard limits except where noted.



BLOCK DIAGRAM

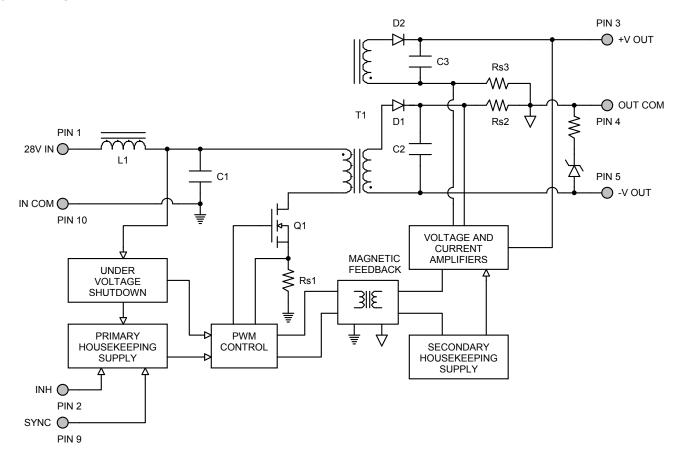


Figure 2

CONNECTION DIAGRAM

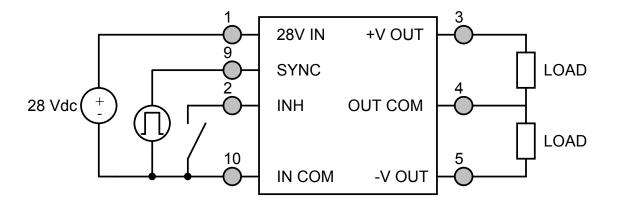


Figure 3



INHIBIT DRIVE CONNECTION DIAGRAMS

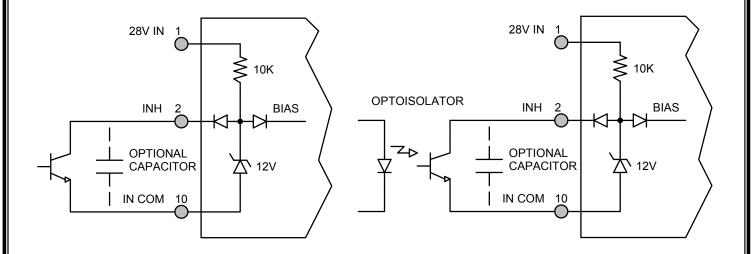


Figure 4 – Internal Inhibit Circuit and Recommended Drive (Shown with optional capacitor for turn-on delay)

Figure 5 – Isolated Inhibit Drive (Shown with optional capacitor for turn-on delay)

EMI FILTER HOOKUP DIAGRAM

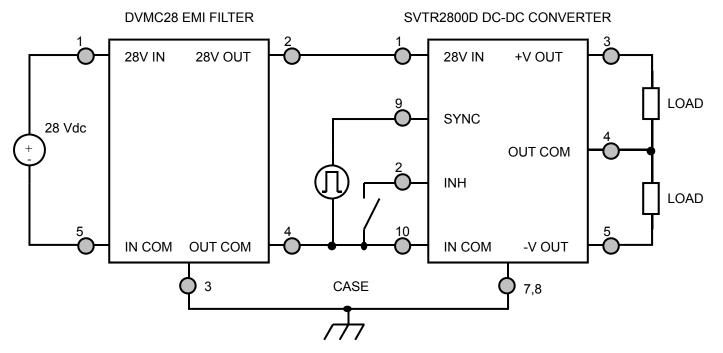
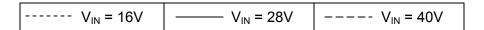


Figure 6 – Converter with EMI Filter



EFFICIENCY PERFORMANCE CURVES (T_{CASE} = 25°C, Full Load, Unless Otherwise Specified)



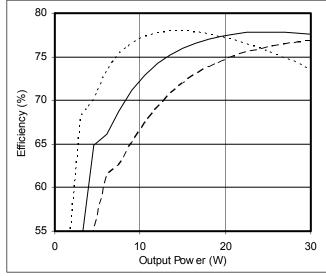


Figure 7 – SVTR2805D Efficiency (%) vs. Output Power (W)

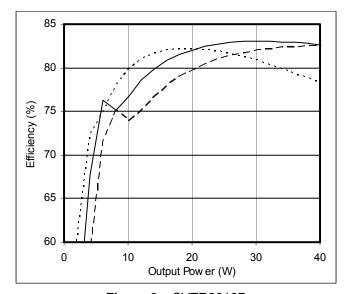


Figure 8 – SVTR2812D Efficiency (%) vs. Output Power (W)

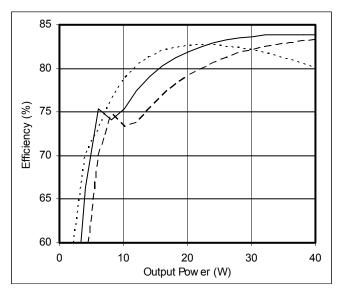


Figure 9 – SVTR2815D Efficiency (%) vs. Output Power (W)



CROSS REGULATION CURVES (T_{CASE} = 25°C, Full Load, Unless Otherwise Specified)



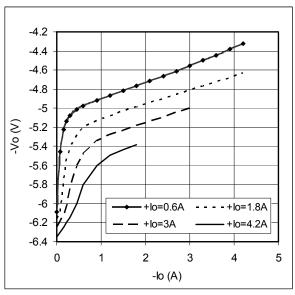


Figure 10 – SVTR2805D -Vout (V) vs. -lout (A)

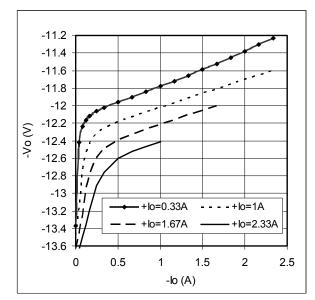


Figure 11 – SVTR2812D -Vout (V) vs. -lout (A)

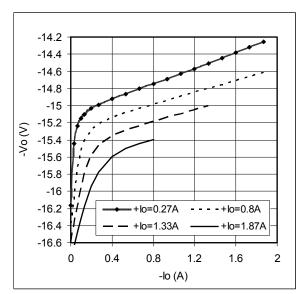
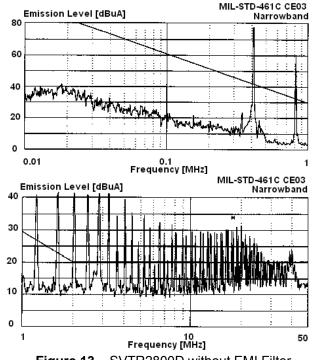
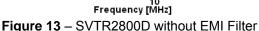


Figure 12 – SVTR2815D -Vout (V) vs. -lout (A)



EMI PERFORMANCE CURVES (T_{CASE} = 25°C, V_{IN} = +28V ± 5%, Full Load, Unless Otherwise Specified)





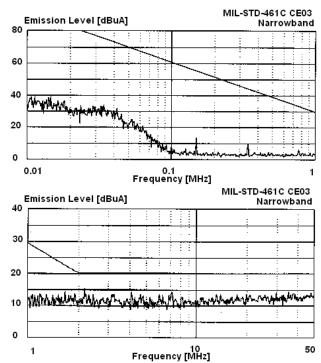


Figure 14 - SVTR2800D with EMI Filter

RADIATION HARDNESS ASSURANCE (RHA)

The SVTR series radiation performance is guaranteed through the use of hardened semiconductor components, radiation lot acceptance testing (RLAT) of non-hardened components, and characterization of the completed hybrid according to VPT's Radiation Hardness Assurance (RHA) plan per MIL-PRF-38534. Appendix G. Post radiation end of life performance limits are determined by worst case analysis.

As part of qualification, one representative model of the hybrid converter family is characterized for total ionizing dose (TID). TID is tested to 60 krad(Si). Subsequent performance is guaranteed to 30 krad(Si) by 2 times margin. Characterization is performed at high dose rate (HDR) in accordance with condition C (minimum dose rate of 30 rad(Si)/s) of method 1019 of MIL-STD-883, and at low dose rate (LDR) in accordance with condition D of method 1019 of MIL-STD-883. A minimum of 1 biased sample and 1 unbiased sample is tested. After radiation exposure, converter testing is performed at 25 °C per standard datasheet limits. The radiation exposure test circuit is given in Figure 15.

Also as part of qualification, one representative model of the hybrid converter family is characterized for Single Event Effects (SEE). The specific test LET is specified on the first page of the datasheet and is tested to a minimum fluence of 1x10⁶ particles/cm². The characterization is performed at nominal input voltage at 25 °C in air. The radiation exposure test circuit is specified in Figure 16.



RADIATION HARDNESS ASSURANCE (continued)

Continued compliance is guaranteed by component testing and analysis. Critical semiconductor components, unless procured with manufacturer radiation guarantees, are subjected to RLAT at HDR in accordance with condition C of method 1019 of MIL-STD-883. Semiconductors which have been shown to exhibit ELDRS are subject to RLAT at LDR in accordance with condition D of method 1019 of MIL-STD-883. RLAT is not performed on inherently radiation hard semiconductor component technologies including zeners, diodes, and small signal BJTs.

RHA TEST CIRCUIT DIAGRAMS

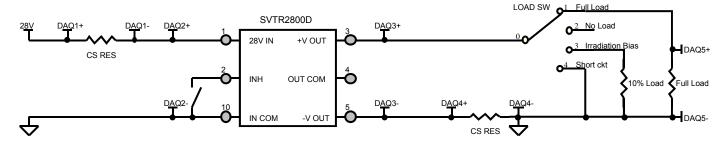


Figure 15 – Radiation exposure circuit (TID)

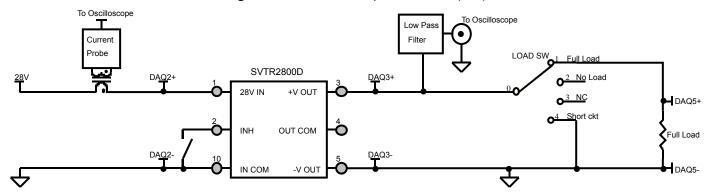
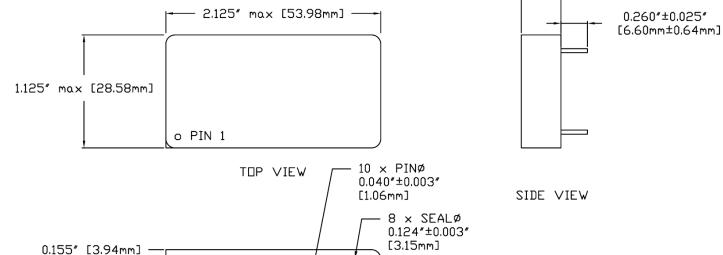


Figure 16 – Radiation exposure circuit (SEE)

- 0.405" max [10.29mm]



PACKAGE SPECIFICATIONS (NON-FLANGED)



0 0 0 **(4)** 0 ⊚ 2 3 BASEPLATE SURFACE 10 9 8 7 6 0.800" [20.32mm] -9 0.255" [6.48mm] 1.600" [40.64mm]

BOTTOM VIEW

NOTES:

- 1. DIMENSIONAL LIMITS ARE ±0.005" UNLESS OTHERWISE STATED.
- 2. CASE TEMPERATURE IS

 MEASURED ON THE CENTER OF
 THE BASEPLATE.
- 3. MATERIALS:

 CASE: STEEL, GOLD OVER

 NICKEL PLATED.

 COVER: KOVAR, NICKEL

 PLATED.

 PINS: COPPER CORED ALLOY

 52, GOLD OVER NICKEL

 PLATED.

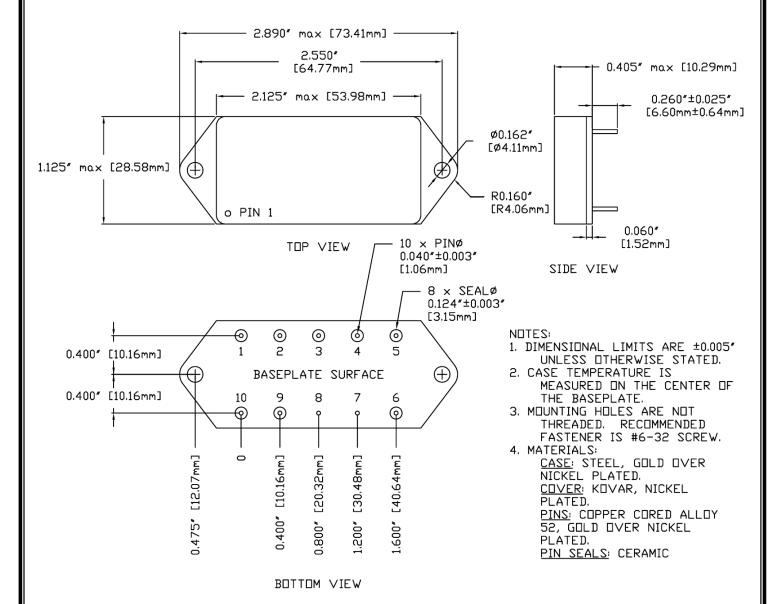
 PIN SEALS: CERAMIC

PIN	FUNCTION	PIN	FUNCTION
1	28V IN	6	CASE
2	INHIBIT	7	CASE
3	+V OUT	8	CASE
4	OUT COM	9	SYNC
5	-V OUT	10	IN COM

Figure 17 – Non-Flanged Package and Pinout



PACKAGE SPECIFICATIONS (FLANGED)



PIN	FUNCTION	PIN	FUNCTION
1	28V IN	6	CASE
2	INHIBIT	7	CASE
3	+V OUT	8	CASE
4	OUT COM	9	SYNC
5	-V OUT	10	IN COM

Figure 18 – Flanged Package and Pinout



PACKAGE PIN DESCRIPTION

Pin	Function	Description
1	28V IN	Positive Input Voltage Connection
2	INHIBIT	Logic Low = Disabled Output. Connecting the inhibit pin to input common causes converter shutdown. Logic High = Enabled Output. Unconnected or open collector TTL.
3	+V OUT	Positive Output Voltage Connection
4	OUT COM	Output Common Connection
5	-V OUT	Negative Output Voltage Connection
6	CASE	Case Connection
7	CASE	Case Connection
8	CASE	Case Connection
9	SYNC	Synchronization Signal
10	IN COM	Input Common Connection



ENVIRONMENTAL SCREENING (100% Tested Per MIL-STD-883 as referenced to MIL-PRF-38534)

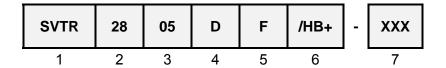
Screening	MIL-STD-883	Class H+ /H+	Class K /K	Engineering Model ⁵ /EM
Non-Destructive Bond Pull	Method 2023 ³	•	•	•
Internal Visual	Method 2017, 2032 Internal Procedure	•	•	•
Temperature Cycling	Method 1010, Condition C	•	•	
Constant Acceleration	Method 2001, 3000g, Y1 Direction	•	•	
PIND	Method 2020, Condition A ²	•	•	
Pre Burn-In Electrical	100% at 25°C		•	
Burn-In	Method 1015, 320 hours at +125°C Method 1015, 160 hours at +125°C 24 Hours at +125°C	•	•	•
Final Electrical	MIL-PRF-38534, Group A ¹ 100% at 25°C	•	•	•
Hermeticity	Method 1014, Fine Leak, Condition A Method 1014, Gross Leak, Condition C Dip (1 x 10 ⁻³)	•	•	•
Radiography	Method 2012 ⁶		•	
External Visual	Method 2009	•	•	•

Notes:

- 1. 100% R&R testing at –55°C, +25°C, and +125°C with all test data included in product shipment.
- 2. PIND test Certificate of Compliance included in product shipment.
- 3. Non-Destructive bond pull per Method 2023 performed.
- 4. Please contact your sales representative or the VPT Inc. Sales Department for more information concerning additional environmental screening and testing options desired.
- 5. Engineering models utilize only the standard screening specified and are not considered compliant for flight use.
- 6. Radiographic test Certificate of Compliance and film(s) included in product shipment.



ORDERING INFORMATION



(1) (2) (3)

Product Series		al Input tage	Output Voltage		Number of Outputs	
SVTR	28	28 Volts	05 12 15	± 5 Volts ± 12 Volts ± 15 Volts	D	Dual

(5) (6)

Package Option		Screening Code		Additional Screening Code
None F	Non-Flanged Flanged	/EM /H+ /K	Engineering Model Class H+ Class K	Contact Sales

Note: Engineering models utilize only the standard screening specified and are not considered compliant for flight use. These models are intended for low volume engineering characterization. The customer must place the following statement on each line item of their purchase order(s) for /EM units when ordering engineering models:

"(<u>Customer Name</u>) acknowledges that the /EM unit listed in this line item is not permitted for flight use and will be used for Engineering characterization only."

Please contact your sales representative or the VPT Inc. Sales Department for more information concerning additional environmental screening and testing, different input voltage, output voltage, power requirement, source inspection, and/or special element evaluation for space or other higher quality applications.



SMD (STANDARD MICROCIRCUIT DRAWING) NUMBERS

Standard Microcircuit	SVTR2800D Series
Drawing (SMD)	Similar Part Number
5962P1122301HXC	SVTR2805D/H+
5962P1122301HYC	SVTR2805DF/H+
5962P1122301KXC	SVTR2805D/K
5962P1122301KYC	SVTR2805DF/K
5962P1122302HXC	SVTR2812D/H+
5962P1122302HYC	SVTR2812DF/H+
5962P1122302KXC	SVTR2812D/K
5962P1122302KYC	SVTR2812DF/K
5962P1122303HXC	SVTR2815D/H+
5962P1122303HYC	SVTR2815DF/H+
5962P1122303KXC	SVTR2815D/K
5962P1122303KYC	SVTR2815DF/K

Do not use the SVTR2800D Series similar part number for SMD product acquisition. It is listed for reference only. For exact specifications for the SMD product, refer to the SMD drawing. SMDs can be downloaded from the DLA Land and Maritime (Previously known as DSCC) website at http://www.dscc.dla.mil/programs/smcr/. The SMD number listed above is for standard gold-plated lead finish and "P" RHA (Radiation Hardness Assurance) level. Please reference the SMD for other screening levels, lead finishes, and radiation levels. All SMD products are marked with a "Q" on the cover as specified by the QML certification mark requirement of MIL-PRF-38534.

CONTACT INFORMATION

To request a quotation or place orders please contact your sales representative or the VPT Inc. Sales Department at:

Phone: (425) 353-3010 Fax: (425) 353-4030 E-mail: vptsales@vpt-inc.com

All information contained in this datasheet is believed to be accurate, however, no responsibility is assumed for possible errors or omissions. The products or specifications contained herein are subject to change without notice.